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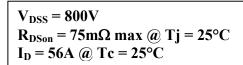


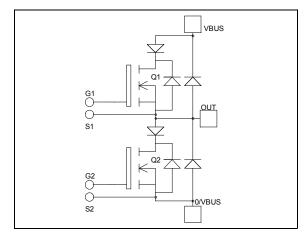






Phase leg Series & SiC parallel diodes Super Junction MOSFET Power Module





## Application

- Motor control
- Switched Mode Power Supplies
- Uninterruptible Power Supplies

### **Features**

- CoolMOS<sup>TM</sup>
  - Ultra low R<sub>DSon</sub>
  - Low Miller capacitance
  - Ultra low gate charge
  - Avalanche energy rated

### • Parallel SiC Schottky Diode

- Zero reverse recovery
- Zero forward recovery
- Temperature Independent switching behavior
- Positive temperature coefficient on VF
- Kelvin source for easy drive
- Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration



- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant

## All ratings @ $T_j = 25^{\circ}C$ unless otherwise specified

## Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage		800	V
$I_D$	Continuous Drain Current $ T_c = 25^{\circ}C $ $T_c = 80^{\circ}C $		56 43	A
$I_{DM}$	Pulsed Drain current		232	11
$V_{GS}$	Gate - Source Voltage		±30	V
R <sub>DSon</sub>	Drain - Source ON Resistance		75	mΩ
$P_D$	Maximum Power Dissipation $T_c = 25^{\circ}C$		568	W
$I_{AR}$	Avalanche current (repetitive and non repetitive)		17	A
$E_{AR}$	Repetitive Avalanche Energy		0.5	T
$E_{AS}$	Single Pulse Avalanche Energy		670	mJ

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Typ	Max	Unit	
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 800V$ $T_j = 25^{\circ}C$			100		
		$V_{GS} = 0V, V_{DS} = 800V$ $T_j = 125^{\circ}C$			1000	μА	
R <sub>DS(on)</sub>	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 28A$			75	mΩ	
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}$ , $I_D = 4mA$	2.1	3	3.9	V	
$I_{GSS}$	Gate – Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±200	nA	

**Dynamic Characteristics** 

•	Characteristic	Test Conditions	Min	Тур	Max	Unit
$C_{iss}$	Input Capacitance	$V_{GS} = 0V$		9015		
$C_{oss}$	Output Capacitance	$V_{DS} = 25V$		4183		pF
$C_{rss}$	Reverse Transfer Capacitance	f = 1MHz		215		
$Q_{\mathrm{g}}$	Total gate Charge	$V_{GS} = 10V$		364		
$Q_{\mathrm{gs}}$	Gate – Source Charge	$V_{\text{Bus}} = 400V$		48		nC
$Q_{\mathrm{gd}}$	Gate – Drain Charge	$I_D = 56A$		184		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C		10		
$T_{\rm r}$	Rise Time	$V_{GS} = 15V$		13		ns
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 533 \text{V}$ $I_{\text{D}} = 56 \text{A}$		83		
$T_{\mathrm{f}}$	Fall Time	$R_G = 1.2\Omega$		35		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C		583		T
$E_{\text{off}}$	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 533V$ $I_D = 56A, R_G = 1.2\Omega$		556		μJ
$E_{on}$	Turn-on Switching Energy	Inductive switching @ 125°C $V_{GS} = 15V$ , $V_{Bus} = 533V$ $I_D = 56A$ , $R_G = 1.2\Omega$		1020		T
E <sub>off</sub>	Turn-off Switching Energy			684		μJ
$R_{\text{thJC}}$	Junction to Case Thermal Resistance	ce			0.22	°C/W

Series diode ratings and characteristics

Symbol	Characteristic	aracteristic Test Conditions		Min	Тур	Max	Unit
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage			1000			V
$I_{RM}$	Maximum Reverse Leakage Current	$V_{R}=1000V$				300	μΑ
$I_F$	DC Forward Current		$T_c = 80^{\circ}C$		120		A
		$I_F = 120A$	1		1.9	2.5	V
$V_{\mathrm{F}}$	Diode Forward Voltage	$I_F = 240A$			2.2		
		$I_F = 120A$	$T_j = 125$ °C		1.7		
+	Reverse Recovery Time	$I_F = 120A$ $V_R = 667V$	$T_j = 25^{\circ}C$		280		ne
t <sub>rr</sub>			$T_{j} = 125^{\circ}C$		350		ns
Q <sub>rr</sub>	Reverse Recovery Charge	$\frac{di}{dt} = 400A/\mu s$	$T_j = 25^{\circ}C$		1.52		μC
			$T_{j} = 125^{\circ}C$		7.2		μΟ
$R_{\text{thJC}}$	Junction to Case Thermal Resistance					0.46	°C/W

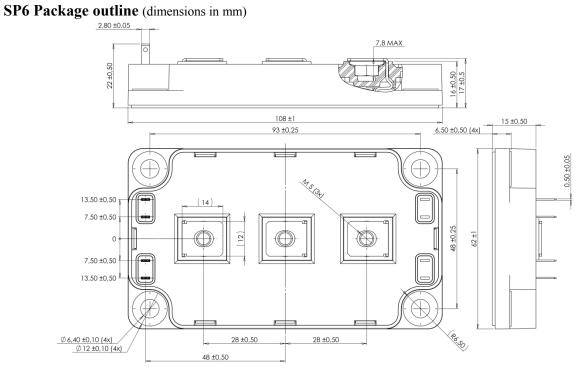


### Parallel diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage			1200			V
$I_{RM}$	Maximum Reverse Leakage Current	V <sub>R</sub> =1200V	$T_j = 25^{\circ}C$ $T_j = 175^{\circ}C$		300 600	1200 6000	μΑ
$I_{\mathrm{F}}$	DC Forward Current		Tc = 100°C		30		A
$V_{\rm F}$	Diode Forward Voltage	$I_F = 30A$ $T_i = 25^{\circ}C$ $T_j = 175^{\circ}C$			1.6 2.6	1.8 3.0	V
Qc	Total Capacitive Charge	$I_F = 30A, V_R = 1200V$ $di/dt = 1600A/\mu s$			168		nC
	T + 10	$f = 1MHz, V_R = 200V$		2	270		E
Q	Total Capacitance $f = 1MHz, V_R = 400V$		= 400V		198		pF
$R_{thJC}$	Junction to Case Thermal Resistance					0.45	°C/W

Thermal and package characteristics

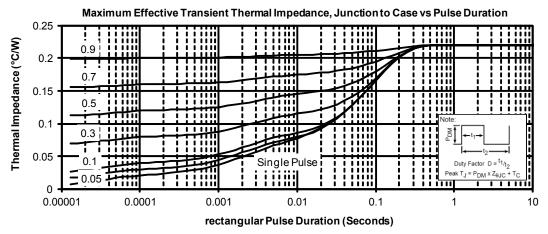
Symbol	Characteristic			Min	Max	Unit
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz					V
$T_{J}$	Operating junction temperature range			-40	150	
$T_{JOP}$	Recommended junction temperature under s	witching condition	ıs	-40	T <sub>J</sub> max -25	°C
$T_{STG}$	Storage Temperature Range				125	
$T_{C}$	Operating Case Temperature	-40	100			
Torque	Mounting torque	To heatsink	M6	3	5	N.m
Torque	Mounting torque	For terminals	M5	2	3.5	18.111
Wt	Package Weight				300	g

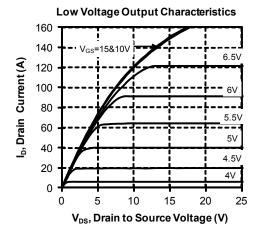


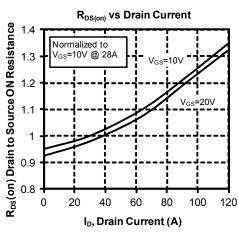
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

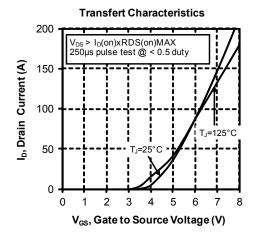


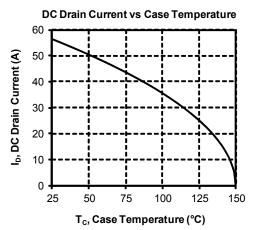
## **Typical CoolMOS Performance Curve**



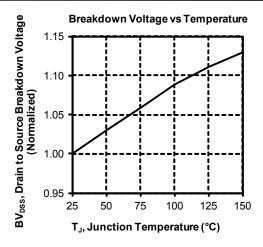


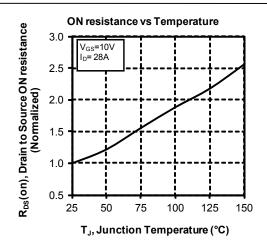


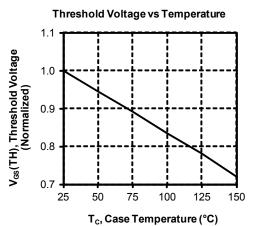


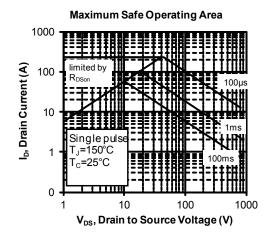


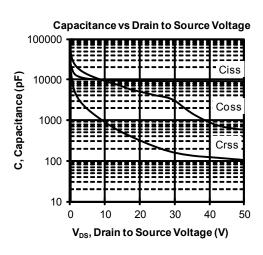


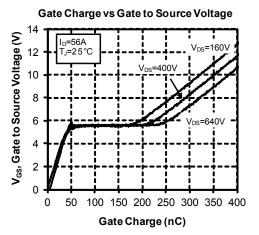




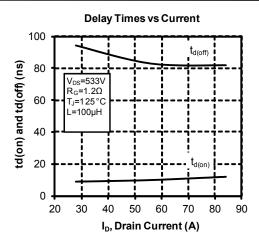


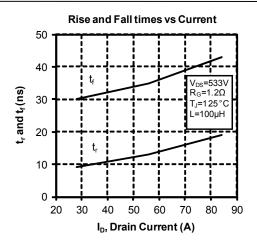


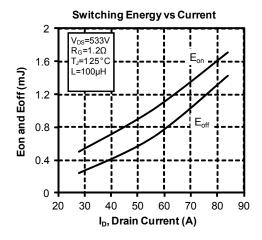


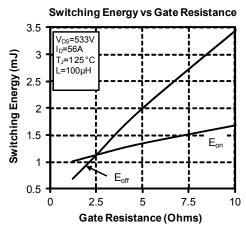


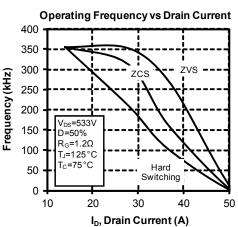


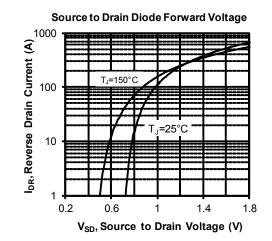






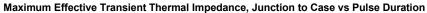


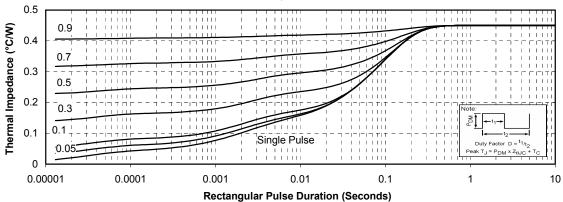


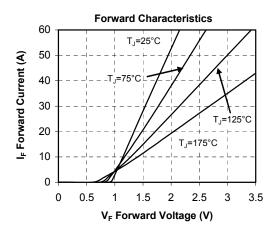


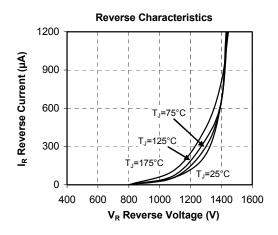


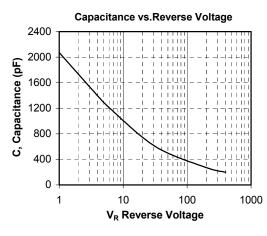
### **Typical SiC Diode Performance Curve**











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